PCN N	20230210001.2								PCN	Date	Febru 2023	ary 13,	
Title:	Qualification	of TI N	lalays	sia a	s an a	dditional /	Assem	nbly	and	Test	site fo	or select o	levices
Custor	Customer Contact: PCN				PCN Manager Dept: Qua					ality Services			
Propos	Proposed 1 st Ship Date		ıg 13,	, 202	23	Sample requests accepted until:				Mar 13, 2023*			
*Samp	ple requests reco	eived	after	[.] Ma	r 13,	2023 wil	l not l	be s	supp	orteo	1.		
Chang	e Type:												
A	ssembly Site	1			Desig	jn				Wa	fer Bu	ump Site	
	ssembly Process					Sheet				Wa	fer Bu	ump Mate	rial
	ssembly Materials				Part	number c	hange					ump Proce	
	, lechanical Specific	ation		\boxtimes	Test					-		ab Site	
	acking/Shipping/L		q			Process				Wa	fer Fa	ab Materia	ıls
			5									ab Process	
					PCI	N Detai	Is						
	iption of Change												
Texas	Instruments is ple	ased t	o ann	noun	ce the	qualificat	tion of	TII	Mala	ysia a	s add	itional As	sembly
	st Site for Select		s liste	ed in	the "I	Product A	ffected	d″ Se	ectio	n. M	ateria	l differenc	ces
betwee	en sites as follows.												
Г		1						- 1					
	Assembly Site	Asser	nbly S	Site	Origin	Assembly	y Cour ode	ntry		Ass	sembl	y City	
	TI Taiwan		TA	Λт			VN		Ch				- 1/
									CI	hung Ho, New Taipei City			
	TI Malaysia		ML	A		M	YS			Κι	iala Lu	Impur	
Materi	ial Differences:												
			TAI					MLA					
	Wire type		0.96mil Au					1.0mil Cu (Die to leadframe) *				*	
	*Wire type Di	e to Di	ie: 0.9	96m	il Au								
	mie cype bi			50111									
Packa	ge Marking Diffe	rence	s:										
			TAI							M	ILA		7
	TI Bug		Include					Replace with "TI" text				-	
						•			Repi			Ι ιελι	-
	**ECAT		Include Value					Remove					
				\T/	YMLLLL					YMLLLL			
					UCC21 G4	1530			00	CC2153	0		
			0	0	04			0					
	Example											1	
					TI LOGO		2005					ATE CODE	
						ONTH DATE (TE CODE	CODE						
						CE CODE		S = ASSY SITE CODE LLLL = LOT TRACE CODE					
					ECAT V				0 = F	PIN 1 IN	DICATO	R	
				0 = F	PIN 1 INC	DICATOR							
** - No	ot all devices have	ECAT	infor	mati	ion inc	luded in t	he sv	mbo	lizat	ion, b	ut for	the ones	that do,
	ormation will be r						,			,			,
	overage, insertions	s, conc	litions	s wil	i rema	in consist	ent w	ith c	urre	nt tes	ting		
	n for Change:												
Continu	uity of supply.												
1) To	align with world te	echnol	ogy tr	rend	s and	use wiring	g with	enh	ance	ed me	chani	cal and	

electrical properties

2) Maximize flexibility within our Assembly/Test production sites. 3) Cu is easier to obtain and stock Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative): None Impact on Environmental Ratings Checked boxes indicate the status of environmental ratings following implementation of this change. If below boxes are checked, there are no changes to the associated environmental ratings. RoHS REACH **Green Status IEC 62474** No Change No Change No Change No Change Changes to product identification resulting from this PCN: Assembly Site TI Taiwan Assembly Site Origin (22L) ASO: TAI TI Malaysia Assembly Site Origin (22L) ASO: MLA Sample product shipping label (not actual product label) TEXAS INSTRUMENTS (1P) SN74LS07NSR MADE IN: Malaysia 2DC: 20: (D) 0336 (a) 2000 31T)LOT: 3959047ML MSL 2 /260C/1 YEAR SEAL DT 4W) TKY(1T) 7523483SI2 MSL 1 /235C/UNLIM 03/29/04 (P) OPT: ITEM: (2P) REV: (V) 0033317 (20L) CSO:SHE (21L) CCO:USA (22L) ASO:MLA (23L) ACO:MYS (L)T0:1750 LBL: 5A **Product Affected:** SN21530QDWKQ1 UCC21530BQDWKRQ1 UCC21540AQDWKRQ1 UCC21320QDWKQ1 UCC21540QDWKRQ1 SN21530QDWKRQ1 UCC21320QDWKRQ1 UCC21530QDWKQ1 SN21540QDWKRQ1 UCC21530BQDWKQ1 UCC21530QDWKRQ1

Qualification Report

Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

Approve Date 31-Jan-2023

Product Attributes

Attributes	Qual Device:	QBS Reference:	QBS Reference:	QBS Reference:	QBS Reference:	QBS Reference:	QBS Reference:
Attributes	UCC21320QDWKRQ1	ISOW7841EQDWEQ1	UCC21520QDWRQ1	ISO7741FEDWRQ1	IS06741QDWQ1	UCC21520AQDWRQ1	TMP451AQDQERQ1
Automotive Grade Level	Grade 1	Grade 1	Grade 1	Grade 0	Grade 1	Grade 1	Grade 1
Operating Temp Range (C)	-40 to 125	-40 to 125	-40 to 125	-40 to 150	-40 to 125	-40 to 125	-40 to 125
Product Function	Power Management	Interface	Power Management	Interface	Interface	Power Management	Power Management
Wafer Fab Supplier	DP1DM5, DP1DM5, DP1DM5	DP1DM5, DP1DM5	DP1DM5, DP1DM5	MH8, MH8	MH8, MH8	MH8, MH8, MH8	DP1DM5
Assembly Site	MLA	TAI	TAI	TAI	MLA	MLA	UTL1
Package Group	SOIC	SOIC	SOIC	SOIC	SOIC	SOIC	QFN
Package Designator	DWK	DWE	DW	DW	DW	DW	DQF
Pin Count	14	16	16	16	16	16	8

QBS: Qual By Similarity

Qual Device UCC21320QDWKRQ1 is qualified at MSL2 260C

	_			Dut		iyea a				ar barnpie	5120 / 11			
Туре	=	Test Spec	Min Lot Qty	SS/ Lot	Test Name	Condition	Duration	Qual Device: UCC21320QDWKRQ1	QBS Reference: ISOW7841FQDWEQ1	QBS Reference: UCC21520QDWRQ1	QBS Reference: ISO7741FEDWRQ1	QBS Reference: ISO6741QDWQ1	QBS Reference: UCC21520AQDWRQ1	QBS Reference: TMP451AQDQFRQ1
Test Group /	A - Acce	lerated Environ		ress Tes	ts									
PC	A1	JEDEC J- STD-020 JESD22- A113	3	77	Preconditioning	MSL2 260C	1 Step	No Fails	-	-	-	No Fails	-	
PC	A1	JEDEC J- STD-020 JESD22- A113	3	77	Preconditioning	MSL3 260C	1 Step			-		-	No Fails	
HAST	A2	JEDEC JESD22- A110	3	77	Biased HAST	130C/85%RH	96 Hours	•				3/231/0	3/231/0	
AC/UHAST	A3	JEDEC JESD22- A102/JEDEC JESD22- A118	3	77	Autoclave	121C/15psig	96 Hours	3/231/0	-	-	-	3/231/0	3/231/0	-
тс	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle	-65C/150C	500 Cycles	3/231/0	-	-	-	3/231/0	3/231/0	-
HTSL	A6	JEDEC JESD22- A103	1	45	High Temperature Storage Life	150C	1000 Hours	-				3/135/0	-	
HTSL	A6	JEDEC JESD22- A103	1 Cinuda	45	High Temperature Storage Life	175C	500 Hours						3/135/0	
Test Group I	B - Acce	lerated Lifetime	: Simula	tion Test	s									
HTOL	B1	JEDEC JESD22- A108 JEDEC	1	77	Life Test	125C	1000 Hours	-	3/231/0	3/231/0	•	3/231/0	1/77/0	
HTOL	B1	JESD22- A108 JEDEC	1	77	Life Test	150C	1000 Hours	-	•	-	3/231/0	-	-	•
ELFR	B1 B2	JESD22- A108 AEC Q100-	1	77	Life Test Early Life	150C	408 Hours 48	•	- 3/840/3 ¹	-	•	-	-	3/231/0
ELFR	82	008	1	"	Failure Rate	1250	Hours 24	•	3/840/3*		•		-	·
ELFR	B2	AEC Q100- 008	1	77	Early Life Failure Rate	150C	Hours	•	•	•	•	•	-	3/2400/0
ELFR	B2	AEC Q100- 008	1	77	Early Life Failure Rate	150C	48 Hours	-	-	•	3/2400/0	-	-	
Test Group	C - Pack	age Assembly	Integrity	y Tests										
WBS	C1	AEC Q100- 001	1	30	Wire Bond Shear	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0
WBP	C2	MIL-STD883 Method 2011	1	30	Wire Bond Pull	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0
SD	C3	JEDEC J- STD-002	1	15	PB Solderability	>95% Lead Coverage			1/15/0	1/15/0	1/15/0	1/15/0	1/15/0	
SD	СЗ	JEDEC J- STD-002	1	15	PB-Free Solderability	>95% Lead Coverage			1/15/0	1/15/0	1/15/0	1/15/0	1/15/0	
PD	C4	JEDEC JESD22- B100 and	1	10	Physical Dimensions	Cpk>1.67		3/30/0	2/20/0	3/30/0	3/30/0	3/30/0	3/30/0	3/30/0
Test Group	D - Die F	B108 abrication Reli	ability Tr	ests										
ЕМ	D1	JESD61		-	Electromigration	-		Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
TDDB	D2	JESD35	-		Time Dependent Dielectric Breakdown			Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
нсі	D3	JESD60 & 28	-	-	Hot Carrier Injection	-		Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology	Completed Per Process Technology	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
NBTI	D4	-	-	-	Negative Bias Temperature Instability	-		Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Requirements Completed Per Process Technology	Completed Per Process Technology	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
SM	D5				Stress Migration			Completed Per Process Technology	Completed Per Process Technology	Completed Per Process Technology	Requirements Completed Per Process Technology	Completed Per Process Technology	Completed Per Process Technology	Completed Per Process Technology
								Requirements	Requirements	Requirements	Requirements	Requirements	Requirements	Requirements
		rical Verificatio					2000							
ESD	E2	002	1	3	ESD HBM	-	Volts	•	1/3/0	1/3/0	1/3/0	1/3/0	-	1/3/0
ESD	E3	AEC Q100- 011	1	3	ESD CDM		500 Volts	1/3/0	1/3/0	1/3/0	1/3/0	1/3/0	1/3/0	1/3/0
LU	E4	AEC Q100- 004	1	6	Latch-Up Electrical	Per AEC Q100-004 Cpk>1.67	-	•	1/6/0	1/6/0	1/6/0	1/6/0	-	1/6/0
ED	E5	AEC Q100- 009	3	30	Electrical Distributions	Room, hot, and cold	-	1/30/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles Ambient Operating Temperature by Automotive Grade Level: Grade 0 (or E): -40C to +150C Grade 1 (or Q): -40C to +125C Grade 2 (or T): -40C to +105C Grade 3 (or I) : -40C to +85C E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level): Room/Hot/Cold : HTOL, ED Room/Hot : THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU Room : AC/uHAST Quality and Environmental data is available at TI's external Web site: http://www.ti.com

Qualification Report

Automotive New Product Qualification Summary (As per AEC-Q100, AEC-Q006 and JEDEC Guidelines)

Approve Date 16-Feb-2021

Product Attributes

Attributes	Qual Device: <u>ISO6741QDWRQ1</u>
Operating Temp Range	-40 to +125 C
Automotive Grade Level	Grade 1
Product Function	Interface
Wafer Fab Supplier	MH8
As sembly Site	MLA
Package Type	SOIC
Package Designator	DW
Ball/Lead Count	16

- QBS: Qual By Similarity

- Device ISO6741QDWRQ1 contains multiple dies.

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Spec	Min Lot Qty	SS/Lot	Test Name / Condition	Duration	Qual Device: ISO6741QDWRQ1
Test G	roup	A – Accelerat	ted Envi	ironment Str	ess Tests		
PC	A1	-	3	22	SAMAnalysis, Pre Stress	Completed	-
РС	A1	JEDEC J- ST D-020 JESD22- A113	3	77	Preconditioning	Level 2 -260C	No fails
PC	A1	-	3	22	SAM Analysis, Post Stress	Completed	2/44/0
HAST	A2	JEDEC JESD22- A110	3	77	Biased HAST, 130C/85%RH	96 Hours	3/231/0
HAST	A2	-	3	1	Cross Section, Post bHAST 96 Hours	Completed	-
HAST	A2	-	3	30	Wire Bond Shear, Post bHast, 96 Hours	Wires	-
HAST	A2	-	3	30	Bond Pull over Stitch, post bHAST, 96 Hours	Wires	-
HAST	A2	-	3	30	Bond Pull over Ball, Post bHA ST, 96 Hours Wires		-
HAST	A2	JEDEC	3	77	Biased HAST,	192 Hours	3/210/0

Туре	#	Test Spec	Min Lot Qty	SS/Lot	Test Name / Condition	Duration	Qual Device: ISO6741QDWRQ1
		JESD22- A110			130C/85%RH		
HAST	A2	-	3	1	Cross Section, Post bHAST 192 Hours	Completed	3/3/0
HAST	A2	-	3	22	SAM Analysis, Post bHAST, 192 Hours	Completed	3/66/0
HAST	A2	-	3	30	Wire Bond Shear, Post bHast, 192 Hours	Wires	3/90/0
HAST	A2	-	3	30	Bond Pull over Stitch, post bHAST, 192 Hours	Wires	3/90/0
HAST	A2	-	3	30	Bond Pull over Ball, Post bHAST, 192 Hours	Wires	3/90/0
тс	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle, - 65/150C	500 Cycles	3/231/0
тс	A4	-	3	1	Cross Section, Post T/C 500 Cycles	Completed	-
тс	A4	-	3	22	SAMAnalysis, Post T/C, 500 Cycles	Completed	-
тс	A4	-	3	30	Wire Bond Shear, Post T/C 500 Cycles	Wires	-
тс	A4	-	3	30	Bond Pull over Stitch Post T/C 500 Cycles	Wires	-
тс	A4	- JEDEC	3	30	Bond Pull over Ball Post T/C 500 Cycles	Wires	-
тс	A4	JESD22- A104 and Appendix 3	3	77	Temperature Cycle, - 65/150C	1000 Cycles	3/210/0
тс	A4	-	3	1	Cross Section, Post T/C 1000 Cycles	Completed	3/3/0
тс	A4	-	3	22	SAMAnalysis, Post T/C, 1000 Cycles	Completed	3/66/0
тс	A4	-	3	30	Wire Bond Shear, Post T/C 1000 Cycles	Wires	3/90/0
тс	A4	-	3	30	Bond Pull over Stitch, Post T/C, 1000 Cycles	Wires	3/90/0
тс	A4	-	3	30	Bond Pull over Ball, Post T/C, 1000 Cycles	Wires	3/90/0
HTSL	A6	JEDEC JESD22- A103	3	45	High Temp Storage Bake 150C	1000 Hours	3/135/0
HTSL	A6	-	3	1	Cross Section, Post HTSL 1000 Hours	Completed	-
HTSL	A6	JEDEC JESD22- A103	3	44	High Temp Storage Bake 150C	2000 Hours	3/132/0
HTSL	A6	-	3	1	Cross Section, Post HTSL 2000 Hours	Completed	3/3/0
Test G	roup	C – Package	Assem	bly Integrity			
WBS	C1	AEC Q100-001	3	30	Wire Bond Shear, Cpk>1.67	Wires	3/90/0
WBP	C2	MIL- STD883 Method	3	30	Bond Pull over Ball, Cpk >1.67	Wires	3/90/0

Туре	#	Test Spec	Min Lot Qty	SS/Lot	Test Name / Condition	Duration	Qual Device: ISO6741QDWRQ1
		2011					

A1 (PC): Preconditioning:

Performed for THB, Biased HAST, AC, uHAST & TC samples, as applicable.

Ambient Operating Temperature by Automotive Grade Level:

Grade 0 (or E): -40C to +150C Grade 1 (or Q): -40C to +125C Grade 2 (or T): -40C to +105C Grade 3 (or I) : -40C to +85C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

Room/Hot/Cold : HTOL, ED Room/Hot : THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU Room : AC/uHAST

Green/Pb-free Status: Qualified Pb-Free(SMT) and Green

ZVEI ID reference: SEM-PA-08, SEM-PA-13, SEM-PA-18, SEM-TF-01

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

Location	E-Mail
WW PCN Team	<u>PCN ww admin team@list.ti.com</u>

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